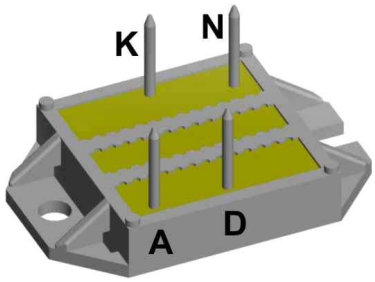
Standard Rectifier Module

1~ Rectifier		
V_{RRM}	=	1200 V
I_{DAV}	=	55 A
I_{FSM}	=	300 A

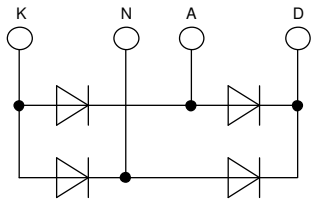
1~ Rectifier Bridge

Part number

VBO54-12NO7



E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

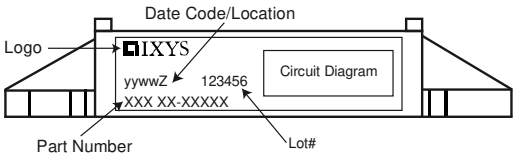
Package: ECO-PAC1

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Rectifier

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			1300	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			1200	V
I_R	*reverse current*	V_R = 1200 V	T_{VJ} = 25°C			40	µA
		V_R = 1200 V	T_{VJ} = 150°C			1.5	mA
V_F	*forward voltage drop*	I_F = 20 A	T_{VJ} = 25°C			1.15	V
		I_F = 40 A				1.34	V
		I_F = 20 A	T_{VJ} = 125°C			1.12	V
		I_F = 40 A				1.32	V
I_{DAV}	*bridge output current*	T_C = 105°C	T_{VJ} = 150°C			55	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 150°C			0.82	V
r_F	*slope resistance* }					12.2	mΩ
R_{thJC}	*thermal resistance junction to case*					1.1	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.4		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			110	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			300	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			325	A
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			255	A
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			275	A
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			450	A^2s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			440	A^2s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 150°C			325	A^2s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			315	A^2s
C_J	*junction capacitance*	V_R = 400 V; f = 1 MHz	T_{VJ} = 25°C		10		pF

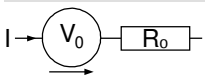
Package ECO-PAC1				Ratings			
Symbol	**Definition**	**Conditions**		**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal				100	A
T_{VJ}	*virtual junction temperature*			-40		150	°C
T_{op}	*operation temperature*			-40		125	°C
T_{stg}	*storage temperature*			-40		125	°C
Weight					19		g
M_D	*mounting torque*			1.4		2	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*		*terminal to terminal*	6.0			mm
$d_{Spb/Apb}$			*terminal to backside*	10.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second	50/60 Hz, RMS; I_{ISOL} ≤ 1 mA	3000			V
		t = 1 minute		2500			V



Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VBO54-12NO7	VBO54-12NO7	Box	25	479543
Alternative	VBO54-12NO7	VBO54-12NO7	Tube	13	521501

Equivalent Circuits for Simulation

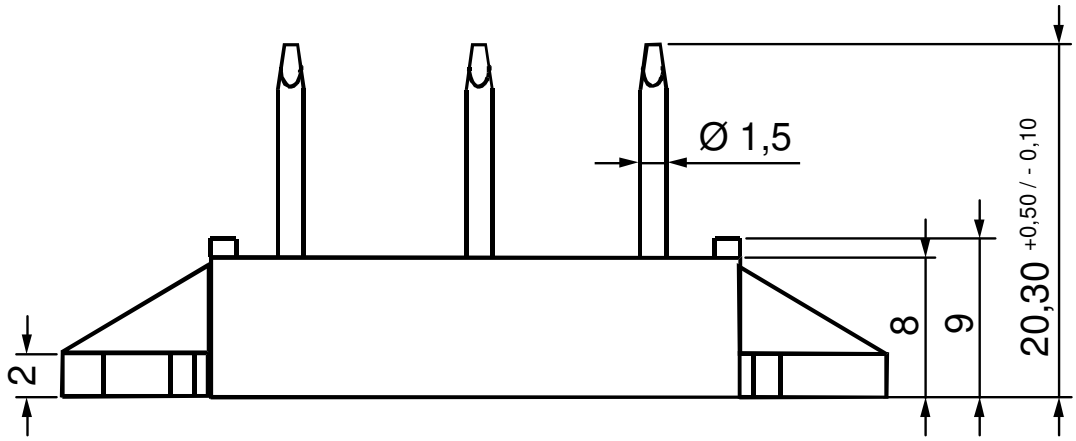
** on die level* T_{VJ} = 150°C

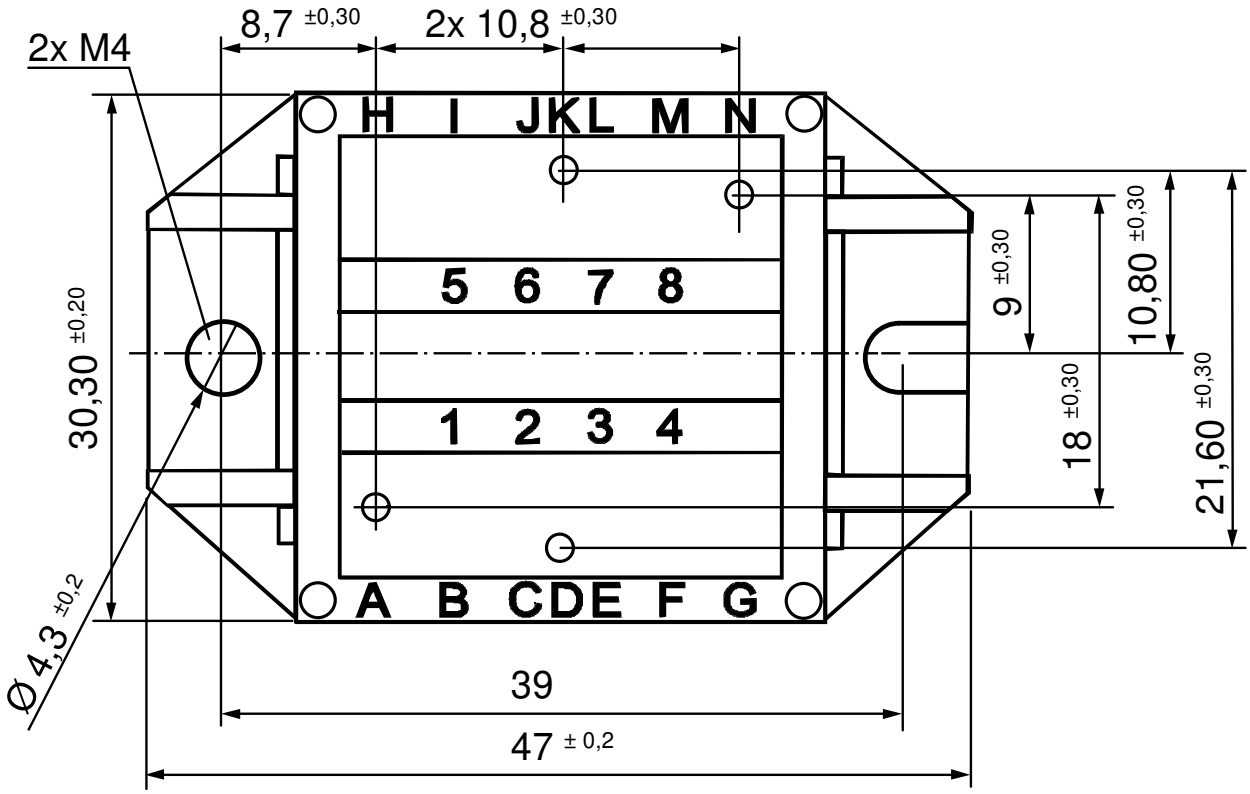


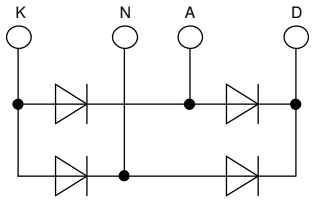
Rectifier

$V_{0\ max}$	*threshold voltage*	0.82	V
$R_{0\ max}$	*slope resistance **	11	mΩ

Outlines ECO-PAC1







Rectifier

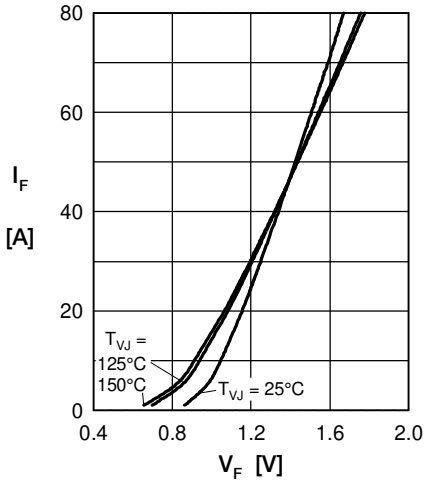


Fig. 1 Forward current versus voltage drop per diode

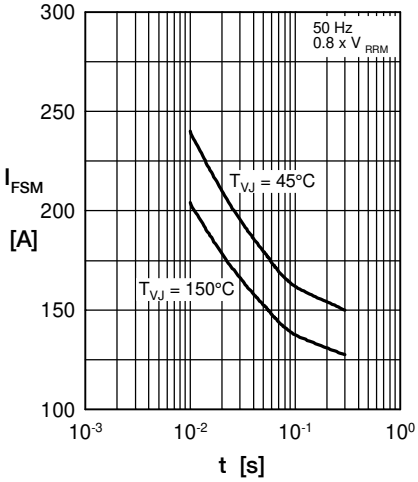


Fig. 2 Surge overload current

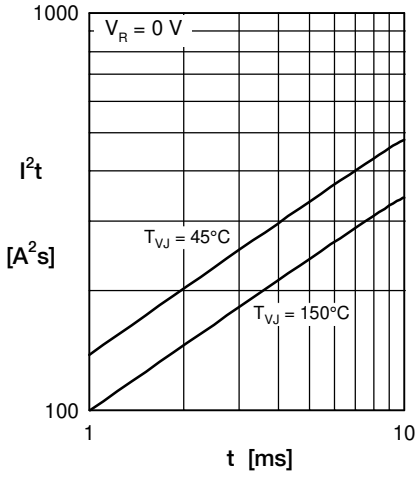


Fig. 3 I^2t versus time per diode

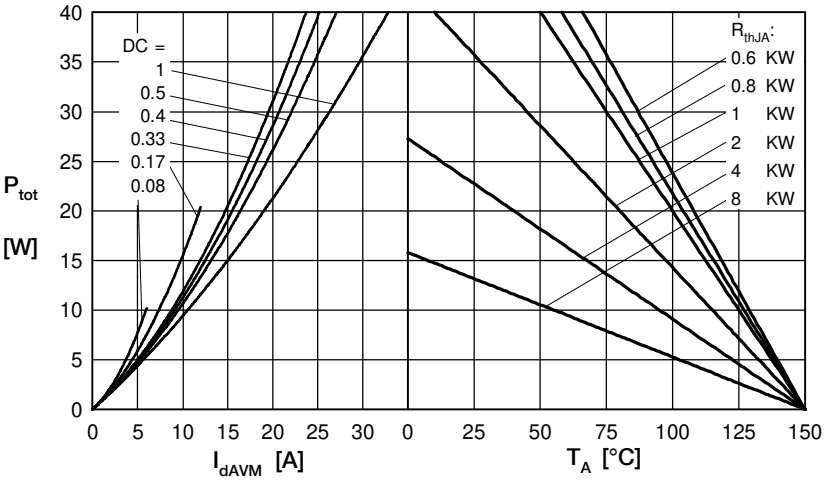


Fig. 4 Power dissipation vs. direct output current & ambient temperature

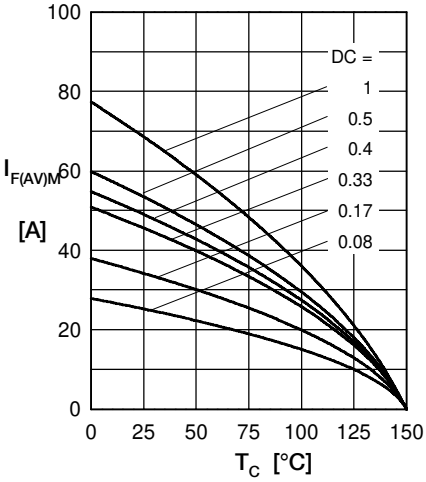


Fig. 5 Max. forward current vs. case temperature

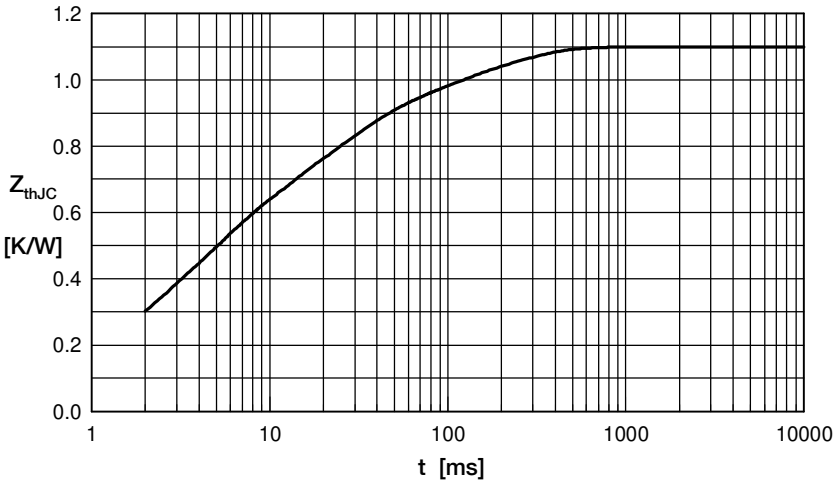


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.05070	0.004
2	0.163	0.0025
3	0.2805	0.0035
4	0.363	0.02
5	0.2228	0.15